

# ANTREX Electronics

Electronic Components Sourcing Information

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## Product Reference Information

**Part Number:** VS-16TTS12STRRPBF  
**Manufacturer:** Vishay General Semiconductor - Diodes Division  
**Package:** TO-263AB (D2PAK)  
**Availability:** Please confirm with sales

### Product Page:

<https://antrexco.com/product/details/vishay-general-semiconductor-diodes-division-vs-16tts12strrpbf.html>

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### Note:

This PDF includes an ANTREX product reference cover page.

The original manufacturer datasheet follows from the next page.

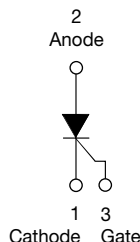
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## Thyristor High Voltage, Surface Mountable Phase Control SCR, 16 A



TO-263AB (D²PAK)



## FEATURES

- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Designed and qualified according JEDEC-JESD47
- Compliant to RoHS Directive 2002/95/EC
- Halogen-free according to IEC 61249-2-21 definition



**RoHS**  
COMPLIANT  
**HALOGEN**  
**FREE**

## PRODUCT SUMMARY

|                   |                   |
|-------------------|-------------------|
| Package           | TO-263AB (D²PAK)  |
| Diode variation   | Single SCR        |
| $I_{T(AV)}$       | 10 A              |
| $V_{DRM}/V_{RRM}$ | 800 V, 1200 V     |
| $V_{TM}$          | 1.4 V             |
| $I_{GT}$          | 60 mA             |
| $T_J$             | - 40 °C to 125 °C |

## APPLICATIONS

- Input rectification (soft start)
- Vishay input diodes, switches and output rectifiers which are available in identical package outlines

## DESCRIPTION

The VS-16TTS..SPbF high voltage series of silicon controlled rectifiers are specifically designed for medium power switching and phase control applications. The glass passivation technology used has reliable operation up to 125 °C junction temperature.

## OUTPUT CURRENT IN TYPICAL APPLICATIONS

| APPLICATIONS                                                          | SINGLE-PHASE BRIDGE | THREE-PHASE BRIDGE | UNITS |
|-----------------------------------------------------------------------|---------------------|--------------------|-------|
| NEMA FR-4 or G-10 glass fabric-based epoxy with 4 oz. (140 µm) copper | 2.5                 | 3.5                | A     |
| Aluminum IMS, $R_{thCA} = 15$ °C/W                                    | 6.3                 | 9.5                |       |
| Aluminum IMS with heatsink, $R_{thCA} = 5$ °C/W                       | 14.0                | 18.5               |       |

## Note

- $T_A = 55$  °C,  $T_J = 125$  °C, footprint 300 mm²

## MAJOR RATINGS AND CHARACTERISTICS

| SYMBOL            | CHARACTERISTICS     | VALUES      | UNITS |
|-------------------|---------------------|-------------|-------|
| $I_{T(AV)}$       | Sinusoidal waveform | 10          | A     |
| $I_{RMS}$         |                     | 16          |       |
| $V_{RRM}/V_{DRM}$ |                     | 800/1200    | V     |
| $I_{TSM}$         |                     | 200         | A     |
| $V_T$             | 10 A, $T_J = 25$ °C | 1.4         | V     |
| $dV/dt$           |                     | 500         | V/µs  |
| $dI/dt$           |                     | 150         | A/µs  |
| $T_J$             |                     | - 40 to 125 | °C    |

## VOLTAGE RATINGS

| PART NUMBER    | $V_{RRM}$ , MAXIMUM PEAK REVERSE VOLTAGE<br>V | $V_{DRM}$ , MAXIMUM PEAK DIRECT VOLTAGE<br>V | $I_{RRM}/I_{DRM}$<br>AT 125 °C<br>mA |
|----------------|-----------------------------------------------|----------------------------------------------|--------------------------------------|
| VS-16TTS08SPbF | 800                                           | 800                                          | 10                                   |
| VS-16TTS12SPbF | 1200                                          | 1200                                         |                                      |

**ABSOLUTE MAXIMUM RATINGS**

| PARAMETER                                             | SYMBOL          | TEST CONDITIONS                                                      | VALUES |      | UNITS         |
|-------------------------------------------------------|-----------------|----------------------------------------------------------------------|--------|------|---------------|
|                                                       |                 |                                                                      | TYP.   | MAX. |               |
| Maximum average on-state current                      | $I_{T(AV)}$     | $T_C = 98\text{ }^{\circ}\text{C}$ , 180° conduction, half sine wave | 10     |      | A             |
| Maximum RMS on-state current                          | $I_{RMS}$       |                                                                      | 16     |      |               |
| Maximum peak, one-cycle, non-repetitive surge current | $I_{TSM}$       | 10 ms sine pulse, rated $V_{RRM}$ applied                            | 170    |      |               |
|                                                       |                 | 10 ms sine pulse, no voltage reapplied                               | 200    |      |               |
| Maximum $I^2t$ for fusing                             | $I^2t$          | 10 ms sine pulse, rated $V_{RRM}$ applied                            | 144    |      | $A^2s$        |
|                                                       |                 | 10 ms sine pulse, no voltage reapplied                               | 200    |      |               |
| Maximum $I^2\sqrt{t}$ for fusing                      | $I^2\sqrt{t}$   | $t = 0.1\text{ ms to }10\text{ ms}$ , no voltage reapplied           | 2000   |      | $A^2\sqrt{s}$ |
| Maximum on-state voltage drop                         | $V_{TM}$        | 10 A, $T_J = 25\text{ }^{\circ}\text{C}$                             | 1.4    |      | V             |
| On-state slope resistance                             | $r_t$           | $T_J = 125\text{ }^{\circ}\text{C}$                                  | 24.0   |      | $m\Omega$     |
| Threshold voltage                                     | $V_{T(TO)}$     |                                                                      | 1.1    |      | V             |
| Maximum reverse and direct leakage current            | $I_{RM}/I_{DM}$ | $T_J = 25\text{ }^{\circ}\text{C}$                                   | 0.5    |      | mA            |
|                                                       |                 | $T_J = 125\text{ }^{\circ}\text{C}$                                  | 10     |      |               |
| Holding current                                       | $I_H$           | Anode supply = 6 V, resistive load, initial $I_T = 1\text{ A}$       | -      | 100  |               |
| Maximum latching current                              | $I_L$           | Anode supply = 6 V, resistive load                                   | 200    |      |               |
| Maximum rate of rise of off-state voltage             | $dV/dt$         |                                                                      | 500    |      | $V/\mu s$     |
| Maximum rate of rise of turned-on current             | $dI/dt$         |                                                                      | 150    |      | $A/\mu s$     |

**TRIGGERING**

| PARAMETER                                   | SYMBOL      | TEST CONDITIONS                                                         | VALUES | UNITS |
|---------------------------------------------|-------------|-------------------------------------------------------------------------|--------|-------|
| Maximum peak gate power                     | $P_{GM}$    |                                                                         | 8.0    | W     |
| Maximum average gate power                  | $P_{G(AV)}$ |                                                                         | 2.0    |       |
| Maximum peak positive gate current          | $+I_{GM}$   |                                                                         | 1.5    | A     |
| Maximum peak negative gate voltage          | $-V_{GM}$   |                                                                         | 10     | V     |
| Maximum required DC gate current to trigger | $I_{GT}$    | Anode supply = 6 V, resistive load, $T_J = -10\text{ }^{\circ}\text{C}$ | 90     | mA    |
|                                             |             | Anode supply = 6 V, resistive load, $T_J = 25\text{ }^{\circ}\text{C}$  | 60     |       |
|                                             |             | Anode supply = 6 V, resistive load, $T_J = 125\text{ }^{\circ}\text{C}$ | 35     |       |
| Maximum required DC gate voltage to trigger | $V_{GT}$    | Anode supply = 6 V, resistive load, $T_J = -10\text{ }^{\circ}\text{C}$ | 3.0    | V     |
|                                             |             | Anode supply = 6 V, resistive load, $T_J = 25\text{ }^{\circ}\text{C}$  | 2.0    |       |
|                                             |             | Anode supply = 6 V, resistive load, $T_J = 125\text{ }^{\circ}\text{C}$ | 1.0    |       |
| Maximum DC gate voltage not to trigger      | $V_{GD}$    | $T_J = 125\text{ }^{\circ}\text{C}$ , $V_{DRM} = \text{Rated value}$    | 0.25   | mA    |
| Maximum DC gate current not to trigger      | $I_{GD}$    |                                                                         | 2.0    |       |

**SWITCHING**

| PARAMETER                     | SYMBOL   | TEST CONDITIONS                     | VALUES | UNITS   |
|-------------------------------|----------|-------------------------------------|--------|---------|
| Typical turn-on time          | $t_{gt}$ | $T_J = 25\text{ }^{\circ}\text{C}$  | 0.9    | $\mu s$ |
| Typical reverse recovery time | $t_{rr}$ | $T_J = 125\text{ }^{\circ}\text{C}$ | 4      |         |
| Typical turn-off time         | $t_q$    |                                     | 110    |         |



| THERMAL - MECHANICAL SPECIFICATIONS             |                |                                         |             |       |
|-------------------------------------------------|----------------|-----------------------------------------|-------------|-------|
| PARAMETER                                       | SYMBOL         | TEST CONDITIONS                         | VALUES      | UNITS |
| Maximum junction and storage temperature range  | $T_J, T_{Stg}$ |                                         | - 40 to 125 | °C    |
| Soldering temperature                           | $T_S$          | For 10 s (1.6 mm from case)             | 240         |       |
| Maximum thermal resistance, junction to case    | $R_{thJC}$     | DC operation                            | 1.3         | °C/W  |
| Typical thermal resistance, junction to ambient | $R_{thJA}$     | PCB mount <sup>(1)</sup>                | 40          |       |
| Approximate weight                              |                |                                         | 2           | g     |
|                                                 |                |                                         | 0.07        | oz.   |
| Marking device                                  |                | Case style D <sup>2</sup> PAK (SMD-220) | 16TTS08S    |       |
|                                                 |                |                                         | 16TTS12S    |       |

**Note**

- <sup>(1)</sup> When mounted on 1" square (650 mm<sup>2</sup>) PCB of FR-4 or G-10 material 4 oz. (140 μm) copper 40 °C/W.  
For recommended footprint and soldering techniques refer to application note #AN-994.

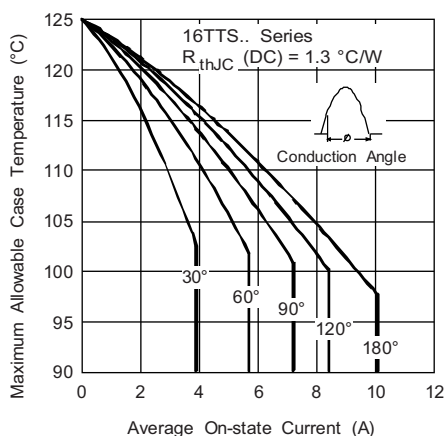


Fig. 1 - Current Rating Characteristics

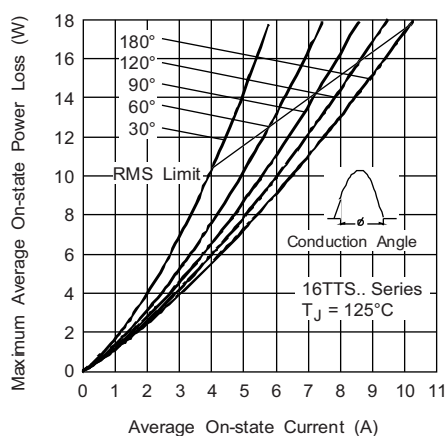


Fig. 3 - On-State Power Loss Characteristics

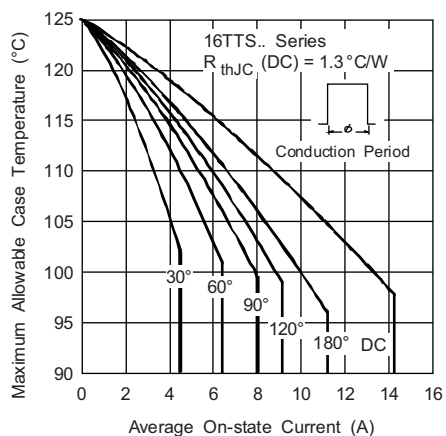


Fig. 2 - Current Rating Characteristics

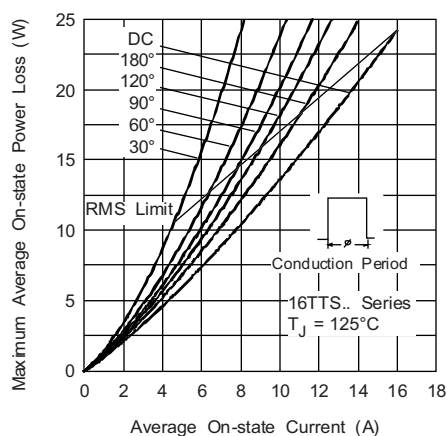


Fig. 4 - On-State Power Loss Characteristics

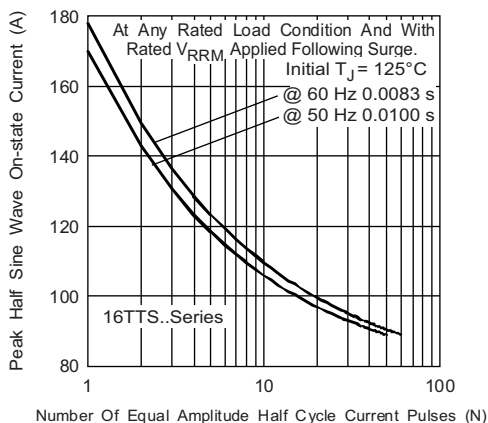


Fig. 5 - Maximum Non-Repetitive Surge Current

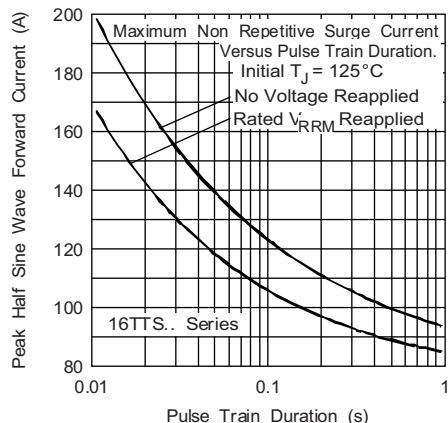


Fig. 6 - Maximum Non-Repetitive Surge Current

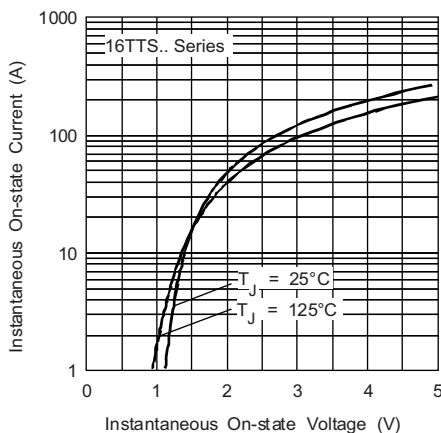


Fig. 7 - On-State Voltage Drop Characteristics

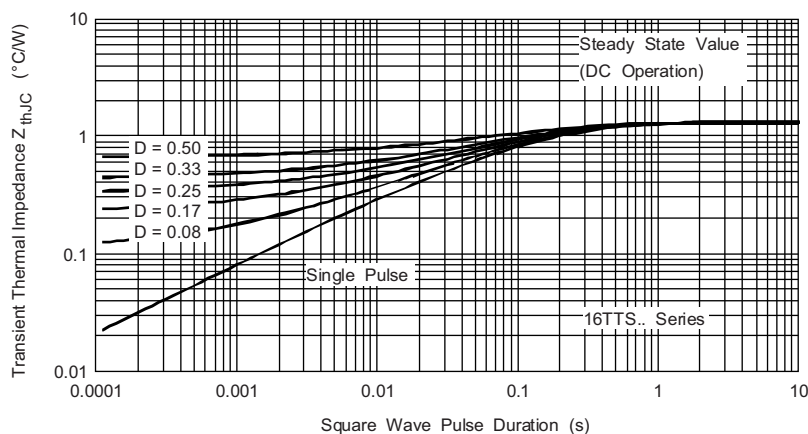


Fig. 8 - Thermal Impedance  $Z_{thJC}$  Characteristics

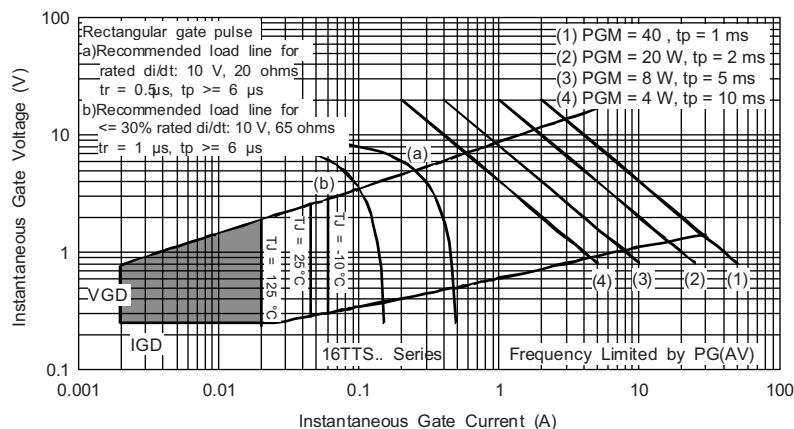


Fig. 9 - Gate Characteristics

## ORDERING INFORMATION TABLE

| Device code | VS-                                                                                                                                                      | 16 | T | T | S | 12 | S | TRL | PbF |
|-------------|----------------------------------------------------------------------------------------------------------------------------------------------------------|----|---|---|---|----|---|-----|-----|
|             | 1                                                                                                                                                        | 2  | 3 | 4 | 5 | 6  | 7 | 8   | 9   |
| 1           | Vishay Semiconductors product                                                                                                                            |    |   |   |   |    |   |     |     |
| 2           | Current rating                                                                                                                                           |    |   |   |   |    |   |     |     |
| 3           | Circuit configuration:<br>T = Single thyristor                                                                                                           |    |   |   |   |    |   |     |     |
| 4           | Package:<br>T = TO-220AC                                                                                                                                 |    |   |   |   |    |   |     |     |
| 5           | Type of silicon:<br>S = Standard recovery rectifier                                                                                                      |    |   |   |   |    |   |     |     |
| 6           | Voltage rating: Voltage code x 100 = $V_{RRM}$                                                                                                           |    |   |   |   |    |   |     |     |
| 7           | S = D <sup>2</sup> PAK version                                                                                                                           |    |   |   |   |    |   |     |     |
| 8           | <ul style="list-style-type: none"> <li>None = Tube</li> <li>TRL = Tape and reel (left oriented)</li> <li>TRR = Tape and reel (right oriented)</li> </ul> |    |   |   |   |    |   |     |     |
| 9           | PbF = Lead (Pb)-free and RoHS compliant                                                                                                                  |    |   |   |   |    |   |     |     |

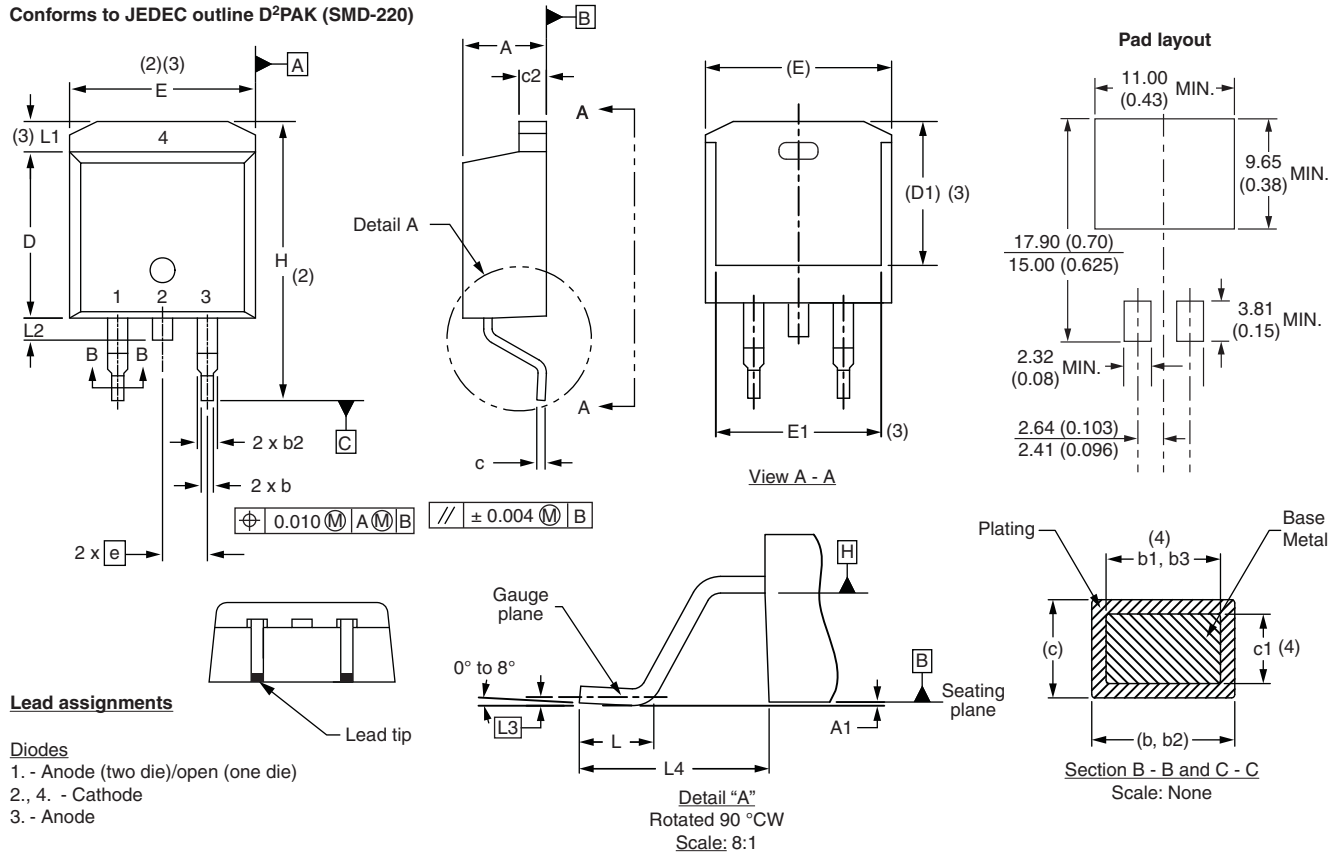
08 = 800 V  
12 = 1200 V

| LINKS TO RELATED DOCUMENTS |                                                                        |
|----------------------------|------------------------------------------------------------------------|
| Dimensions                 | <a href="http://www.vishay.com/doc?95046">www.vishay.com/doc?95046</a> |
| Part marking information   | <a href="http://www.vishay.com/doc?95054">www.vishay.com/doc?95054</a> |
| Packaging information      | <a href="http://www.vishay.com/doc?95032">www.vishay.com/doc?95032</a> |

### D<sup>2</sup>PAK

#### DIMENSIONS in millimeters and inches

Conforms to JEDEC outline D<sup>2</sup>PAK (SMD-220)



| SYMBOL | MILLIMETERS |       | INCHES |       | NOTES |
|--------|-------------|-------|--------|-------|-------|
|        | MIN.        | MAX.  | MIN.   | MAX.  |       |
| A      | 4.06        | 4.83  | 0.160  | 0.190 |       |
| A1     | 0.00        | 0.254 | 0.000  | 0.010 |       |
| b      | 0.51        | 0.99  | 0.020  | 0.039 |       |
| b1     | 0.51        | 0.89  | 0.020  | 0.035 | 4     |
| b2     | 1.14        | 1.78  | 0.045  | 0.070 |       |
| b3     | 1.14        | 1.73  | 0.045  | 0.068 | 4     |
| c      | 0.38        | 0.74  | 0.015  | 0.029 |       |
| c1     | 0.38        | 0.58  | 0.015  | 0.023 | 4     |
| c2     | 1.14        | 1.65  | 0.045  | 0.065 |       |
| D      | 8.51        | 9.65  | 0.335  | 0.380 | 2     |

| SYMBOL | MILLIMETERS |       | INCHES    |       | NOTES |
|--------|-------------|-------|-----------|-------|-------|
|        | MIN.        | MAX.  | MIN.      | MAX.  |       |
| D1     | 6.86        | 8.00  | 0.270     | 0.315 | 3     |
| E      | 9.65        | 10.67 | 0.380     | 0.420 | 2, 3  |
| E1     | 7.90        | 8.80  | 0.311     | 0.346 | 3     |
| e      | 2.54 BSC    |       | 0.100 BSC |       |       |
| H      | 14.61       | 15.88 | 0.575     | 0.625 |       |
| L      | 1.78        | 2.79  | 0.070     | 0.110 |       |
| L1     | -           | 1.65  | -         | 0.066 | 3     |
| L2     | 1.27        | 1.78  | 0.050     | 0.070 |       |
| L3     | 0.25 BSC    |       | 0.010 BSC |       |       |
| L4     | 4.78        | 5.28  | 0.188     | 0.208 |       |

#### Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch
- (7) Outline conforms to JEDEC outline TO-263AB



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